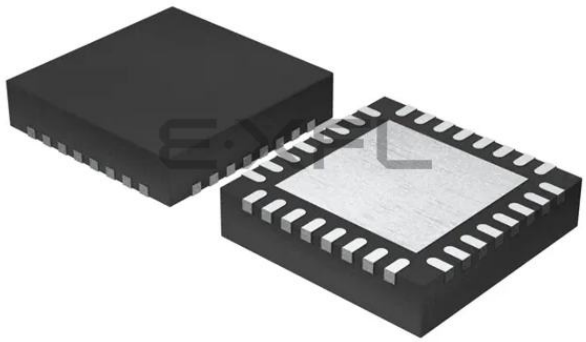

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Applications of "Embedded - Microcontrollers"

Details	
Product Status	Active
Core Processor	ARM® Cortex®-M0+
Core Size	32-Bit Single-Core
Speed	48MHz
Connectivity	I²C, FlexIO, SPI, UART/USART
Peripherals	DMA, I²S, PWM, WDT
Number of I/O	28
Program Memory Size	32KB (32K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	8K x 8
Voltage - Supply (Vcc/Vdd)	1.71V ~ 3.6V
Data Converters	A/D 11x16b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 105°C (TA)
Mounting Type	Surface Mount
Package / Case	32-UFQFN Exposed Pad
Supplier Device Package	32-QFN (5x5)
Purchase URL	https://www.e-xfl.com/product-detail/nxp-semiconductors/mkl17z32vfm4

Table of Contents

The Flash Option (FOPT) register in the Flash Memory module (FTFA_FOPT) allows the user to customize the operation of the MCU at boot time. The register contains read-only bits that are loaded from the NVM's option byte in the flash configuration field. Below is boot flow chart for this device.

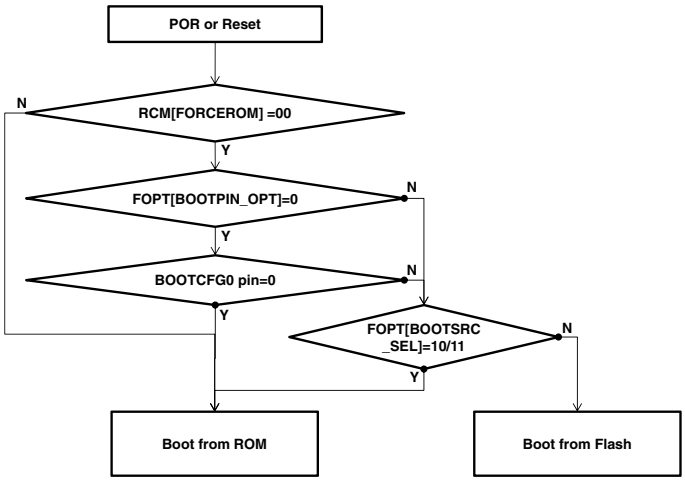


Figure 2. Boot flow chart

The blank chip is default to boot from ROM and remaps the vector table to ROM base address, otherwise, it remaps to flash address.

2.1.6 Clock options

This chip provides a wide range of sources to generate the internal clocks. These sources include internal resistor capacitor (IRC) oscillators, external oscillators, external clock sources, and ceramic resonators. These sources can be configured to provide the required performance and optimize the power consumption.

The IRC oscillators include the high-speed internal resister capacitor (HIRC) oscillator, the low-speed internal resister capacitor (LIRC) oscillator, and the low power oscillator (LPO).

The HIRC oscillator generates a 48 MHz clock.

The LIRC oscillator generates an 8 MHz or 2 MHz clock, and default to 8 MHz system clock on reset. The LIRC oscillator cannot be used in any VLLS modes.

The LPO generates a 1 kHz clock and cannot be used in VLLS0 mode.

Table 6. Peripherals states in different operational modes (continued)

Core mode	Device mode	Descriptions
Deep sleep	Stop	In Stop mode, most peripheral clocks are disabled and placed in a static state. Stop mode retains all registers and SRAMs while maintaining Low Voltage Detection protection. In Stop mode, the ADC, CMP, LPTimer, RTC, and pin interrupts are operational. The NVIC is disabled, but the AWIC can be used to wake up from an interrupt.
	Very Low Power Stop	In VLPS mode, the contents of the SRAM are retained. The CMP (low speed), ADC, OSC, RTC, LPTMR, TPM, FlexIO, LPUART, and DMA are operational, LVD and NVIC are disabled, AWIC is used to wake up from interrupt.
	Low Leakage Stop	In LLS mode, the contents of the SRAM and the 32-byte system register file are retained. The CMP (low speed), LLWU, LPTMR, and RTC are operational. The ADC, CRC, DMA, FlexIO, I2C, LPUART, MCG-Lite, NVIC, PIT, SPI, TPM, UART, and COP are static, but retain their programming. The GPIO, and VREF are static, retain their programming, and continue to drive their previous values.
	Very Low Leakage Stop	In VLLS modes, most peripherals are powered off and will resume operation from their reset state when the device wakes up. The LLWU, LPTMR, and RTC are operational in all VLLS modes. In VLLS3, the contents of the SRAM and the 32-byte system register file are retained. The CMP (low speed), and PMC are operational. The GPIO, and VREF are not operational but continue driving. In VLLS1, the contents of the 32-byte system register file are retained. The CMP (low speed), and PMC are operational. The GPIO, and VREF are not operational but continue driving. In VLLS0, the contents of the 32-byte system register file are retained. The PMC is operational. The GPIO is not operational but continues driving. The POR detection circuit can be enabled or disabled.

2.1.9 LLWU

The LLWU module is used to wake MCU from low leakage power mode (LLS and VLLSx) and functional only on entry into a low-leakage power mode. After recovery from LLS, the LLWU is immediately disabled. After recovery from VLLSx, the LLWU continues to detect wake-up events until the user has acknowledged the wake-up event.

This device uses 8 external wakeup pin inputs and 4 internal modules as wakeup sources to the LLWU module.

The following is internal peripheral and external pin inputs as wakeup sources to the LLWU module.

2.2.6 CMP

The device contains one high-speed comparator and two 8-input multiplexers for both the inverting and non-inverting inputs of the comparator. Each CMP input channel connects to both muxes.

The CMP includes one 6-bit DAC, which provides a selectable voltage reference for various user application cases. Besides, the CMP also has several module-to-module interconnects in order to facilitate ADC triggering, TPM triggering, and interfaces.

The CMP has the following features:

- Inputs may range from rail to rail
- Programmable hysteresis control
- Selectable interrupt on rising-edge, falling-edge, or both rising or falling edges of the comparator output
- Selectable inversion on comparator output
- Capability to produce a wide range of outputs such as sampled, digitally filtered
- External hysteresis can be used at the same time that the output filter is used for internal functions
- Two software selectable performance levels: shorter propagation delay at the expense of higher power and Low power with longer propagation delay
- DMA transfer support
- Functional in all modes of operation except in VLLS0 mode
- The filter functions are not available in Stop, VLPS, LLS, or VLLSx modes
- Integrated 6-bit DAC with selectable supply reference source and can be power down to conserve power
- Two 8-to-1 channel mux

2.2.7 RTC

The RTC is an always powered-on block that remains active in all low power modes. The time counter within the RTC is clocked by a 32.768 kHz clock sourced from an external crystal using the oscillator or clock directly from RTC_CLKIN pin.

RTC is reset on power-on reset, and a software reset bit in RTC can also initialize all RTC registers.

The RTC module has the following features

- 32-bit seconds counter with roll-over protection and 32-bit alarm

2.2.10 CRC

This device contains one cyclic redundancy check (CRC) module which can generate 16/32-bit CRC code for error detection.

The CRC module provides a programmable polynomial, WAS, and other parameters required to implement a 16-bit or 32-bit CRC standard.

The CRC module has the following features:

- Hardware CRC generator circuit using a 16-bit or 32-bit programmable shift register
- Programmable initial seed value and polynomial
- Option to transpose input data or output data (the CRC result) bitwise or bytewise.
- Option for inversion of final CRC result
- 32-bit CPU register programming interface

2.2.11 UART

This device contains a basic universal asynchronous receiver/transmitter (UART) module with DMA function supported. Generally, this module is used in RS-232, RS-485, and other communications and supports LIN slave operation and ISO7816.

The UART module has the following features:

- Full-duplex operation
- 13-bit baud rate selection with /32 fractional divide, based on the module clock frequency
- Programmable 8-bit or 9-bit data format
- Programmable transmitter output polarity
- Programmable receive input polarity
- Up to 14-bit break character transmission.
- 11-bit break character detection option
- Two receiver wakeup methods with idle line or address mark wakeup
- Address match feature in the receiver to reduce address mark wakeup ISR overhead
- Ability to select MSB or LSB to be first bit on wire
- Support for ISO 7816 protocol to interface with SIM cards and smart cards
- Receiver framing error detection
- Hardware parity generation and checking

- Full-duplex or single-wire bidirectional mode
- Programmable transmit bit rate
- Double-buffered transmit and receive data register
- Serial clock phase and polarity options
- Slave select output
- Mode fault error flag with CPU interrupt capability
- Control of SPI operation during wait mode
- Selectable MSB-first or LSB-first shifting
- Programmable 8- or 16-bit data transmission length
- Receive data buffer hardware match feature
- 64-bit FIFO mode for high speed/large amounts of data transfers
- Support DMA

2.2.14 I2C

This device contains two I2C modules, which support up to 1 Mbits/s by dual buffer features, and address match to wake MCU from the low power mode.

I2C modules support DMA transfer, and the interrupt condition can trigger DMA request when DMA function is enabled.

The I2C modules have the following features:

- Support for system management bus (SMBus) Specification, version 2
- Software programmable for one of 64 different serial clock frequencies
- Software-selectable acknowledge bit
- Arbitration-lost interrupt with automatic mode switching from master to slave
- Calling address identification interrupt
- START and STOP signal generation and detection
- Repeated START signal generation and detection
- Acknowledge bit generation and detection
- Bus busy detection
- General call recognition
- 10-bit address extension
- Programmable input glitch filter
- Low power mode wakeup on slave address match
- Range slave address support
- DMA support
- Double buffering support to achieve higher baud rate

64 LQFP	36 XFBGA	32 QFN	48 QFN	64 MAPBGA	Pin Name	Default	ALT0	ALT1	ALT2	ALT3	ALT4	ALT5	ALT6	ALT7
37	—	—	29	E7	PTB2	ADC0_SE12	ADC0_SE12	PTB2	I2C0_SCL	TPM2_CH0				
38	—	—	30	E8	PTB3	ADC0_SE13	ADC0_SE13	PTB3	I2C0_SDA	TPM2_CH1				
39	—	—	31	E6	PTB16	DISABLED		PTB16	SPI1_MOSI	LPUART0_RX	TPM_CLKIN0	SPI1_MISO		
40	—	—	32	D7	PTB17	DISABLED		PTB17	SPI1_MISO	LPUART0_TX	TPM_CLKIN1	SPI1_MOSI		
41	—	—	—	D6	PTB18	DISABLED		PTB18		TPM2_CH0				
42	—	—	—	C7	PTB19	DISABLED		PTB19		TPM2_CH1				
43	—	—	33	D8	PTC0	ADC0_SE14	ADC0_SE14	PTC0		EXTRG_IN		CMP0_OUT		
44	C5	22	34	C6	PTC1/LLWU_P6/RTC_CLKIN	ADC0_SE15	ADC0_SE15	PTC1/LLWU_P6/RTC_CLKIN	I2C1_SCL		TPM0_CH0			
45	B6	23	35	B7	PTC2	ADC0_SE11	ADC0_SE11	PTC2	I2C1_SDA		TPM0_CH1			
46	B5	24	36	C8	PTC3/LLWU_P7	DISABLED		PTC3/LLWU_P7	SPI1_SCK	LPUART1_RX	TPM0_CH2	CLKOUT		
47	—	—	—	E3	VSS	VSS	VSS							
48	—	—	—	E4	VDD	VDD	VDD							
49	A6	25	37	B8	PTC4/LLWU_P8	DISABLED		PTC4/LLWU_P8	SPI0_PCS0	LPUART1_TX	TPM0_CH3	SPI1_PCS0		
50	A5	26	38	A8	PTC5/LLWU_P9	DISABLED		PTC5/LLWU_P9	SPI0_SCK	LPTMR0_ALT2			CMP0_OUT	
51	B4	27	39	A7	PTC6/LLWU_P10	CMP0_IN0	CMP0_IN0	PTC6/LLWU_P10	SPI0_MOSI	EXTRG_IN		SPI0_MISO		
52	A4	28	40	B6	PTC7	CMP0_IN1	CMP0_IN1	PTC7	SPI0_MISO			SPI0_MOSI		
53	—	—	—	A6	PTC8	CMP0_IN2	CMP0_IN2	PTC8	I2C0_SCL	TPM0_CH4				
54	—	—	—	B5	PTC9	CMP0_IN3	CMP0_IN3	PTC9	I2C0_SDA	TPM0_CH5				
55	—	—	—	B4	PTC10	DISABLED		PTC10	I2C1_SCL					
56	—	—	—	A5	PTC11	DISABLED		PTC11	I2C1_SDA					
57	—	—	41	C3	PTD0	DISABLED		PTD0	SPI0_PCS0		TPM0_CH0		FXIO0_D0	
58	—	—	42	A4	PTD1	ADC0_SE5b	ADC0_SE5b	PTD1	SPI0_SCK		TPM0_CH1		FXIO0_D1	
59	—	—	43	C2	PTD2	DISABLED		PTD2	SPI0_MOSI	UART2_RX	TPM0_CH2	SPI0_MISO	FXIO0_D2	
60	—	—	44	B3	PTD3	DISABLED		PTD3	SPI0_MISO	UART2_TX	TPM0_CH3	SPI0_MOSI	FXIO0_D3	
61	A3	29	45	A3	PTD4/LLWU_P14	DISABLED		PTD4/LLWU_P14	SPI1_PCS0	UART2_RX	TPM0_CH4		FXIO0_D4	
62	B3	30	46	C1	PTD5	ADC0_SE6b	ADC0_SE6b	PTD5	SPI1_SCK	UART2_TX	TPM0_CH5		FXIO0_D5	
63	B2	31	47	B2	PTD6/LLWU_P15	ADC0_SE7b	ADC0_SE7b	PTD6/LLWU_P15	SPI1_MOSI	LPUART0_RX	I2C1_SDA	SPI1_MISO	FXIO0_D6	

Properties	Abbreviation	Descriptions
	H	High level
	L	Low level
Pullup/ pulldown setting after POR	PD	Pullup
	PU	Pulldown
Slew rate after POR	FS	Fast slew rate
	SS	Slow slew rate
Passive Pin Filter after POR	N	Disabled
	Y	Enabled
Open drain	N	Disabled[1]
	Y	Enabled[2]
Pin interrupt	Y	Yes

1. When I2C module is enabled and a pin is functional for I2C, this pin is (pseudo-) open drain enabled. When UART or LPUART module is enabled and a pin is functional for UART or LPUART, this pin is (pseudo-) open drain configurable.
2. PTA20 is a true open drain pin that must never be pulled above VDD.

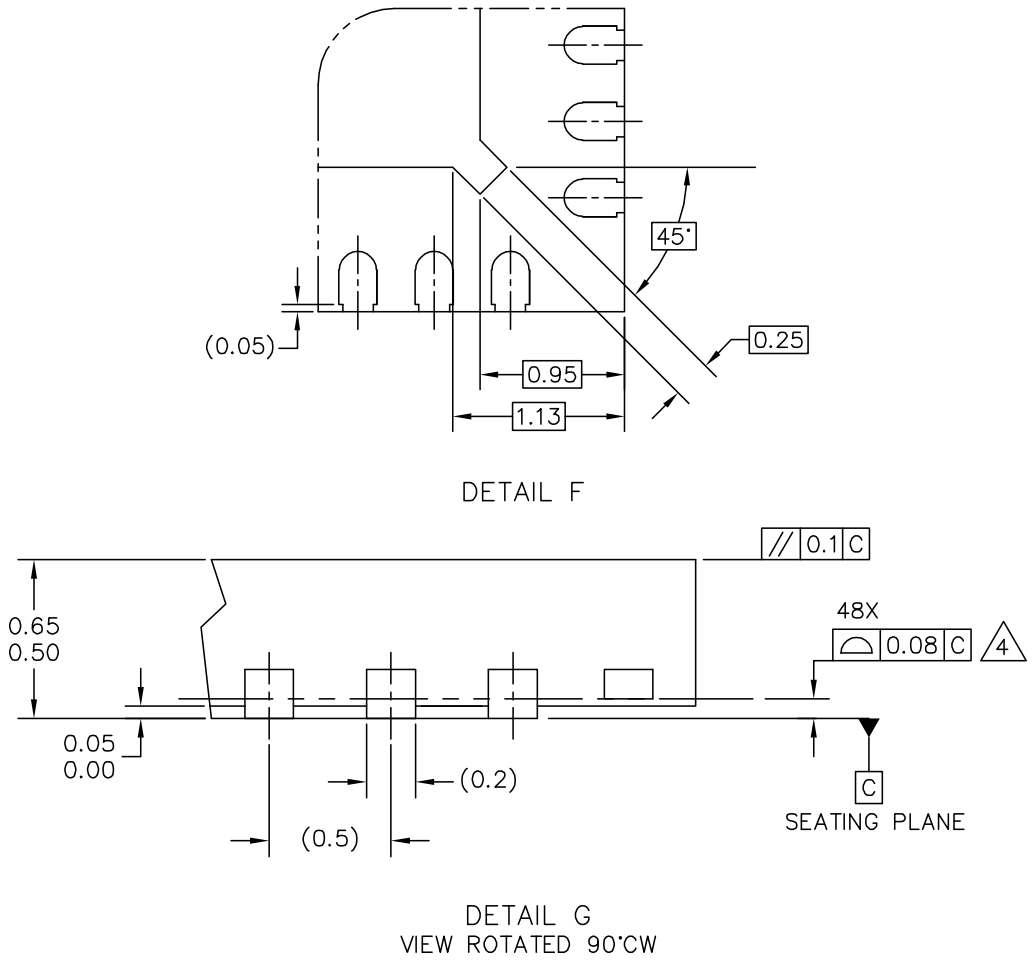
4.3 Module Signal Description Tables

The following sections correlate the chip-level signal name with the signal name used in the module's chapter. They also briefly describe the signal function and direction.

4.3.1 Core modules

Table 9. SWD signal descriptions

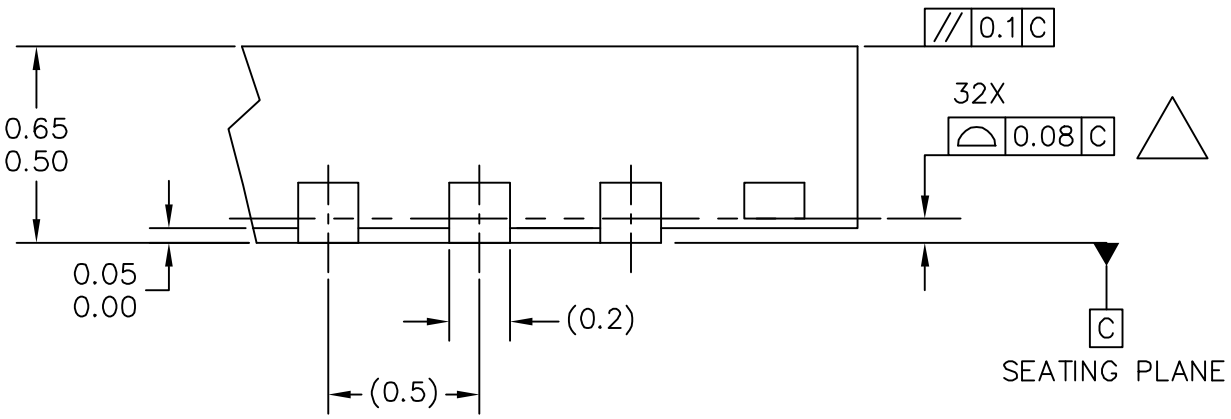
Chip signal name	Module signal name	Description	I/O
SWD_DIO	SWD_DIO	Serial Wire Debug Data Input/Output The SWD_DIO pin is used by an external debug tool for communication and device control. This pin is pulled up internally.	Input / Output
SWD_CLK	SWD_CLK	Serial Wire Clock This pin is the clock for debug logic when in the Serial Wire Debug mode. This pin is pulled down internally.	Input



NOTES:

1. ALL DIMENSIONS ARE IN MILLIMETERS.
2. DIMENSIONING AND TOLERANCING PER ASME Y14.5M–1994.
3. THIS IS A NON–JEDEC REGISTERED PACKAGE.
4. COPLANARITY APPLIES TO LEADS AND DIE ATTACH FLAG.
5. MIN. METAL GAP SHOULD BE 0.2 MM.

Figure 15. 48-pin QFN package dimension 2



DETAIL G
VIEW ROTATED 90°CW

NOTES:

1. ALL DIMENSIONS ARE IN MILLIMETERS.
2. DIMENSIONING AND TOLERANCING PER ASME Y14.5M–1994.
3. THIS IS A NON–JEDEC REGISTERED PACKAGE.
4. COPLANARITY APPLIES TO LEADS AND DIE ATTACH FLAG.
5. MIN. METAL GAP SHOULD BE 0.2 MM.

Figure 18. 32-pin QFN package dimension 2

5 Electrical characteristics

5.1 Ratings

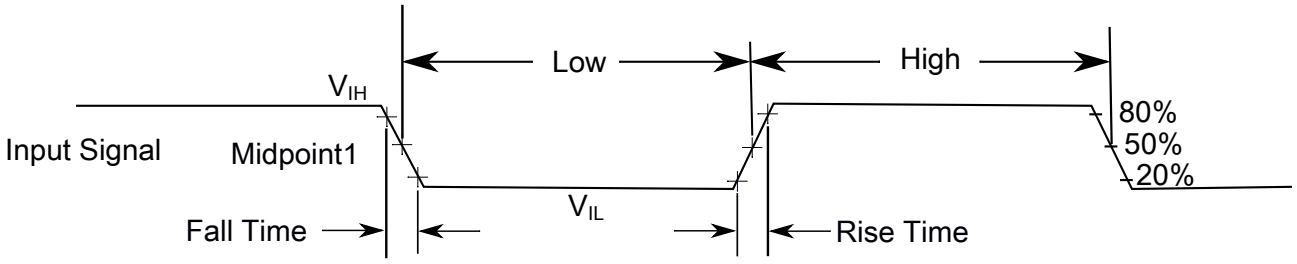
Table 33. Voltage and current absolute operating ratings (continued)

Symbol	Description	Min.	Max.	Unit
V_{IO}	IO pin input voltage	–0.3	V_{DD} + 0.3	V
I_D	Instantaneous maximum current single pin limit (applies to all port pins)	–25	25	mA
V_{DDA}	Analog supply voltage	V_{DD} – 0.3	V_{DD} + 0.3	V

5.2 General

5.2.1 AC electrical characteristics

Unless otherwise specified, propagation delays are measured from the 50% to the 50% point, and rise and fall times are measured at the 20% and 80% points, as shown in the following figure.



The midpoint is V_{IL} + (V_{IH} - V_{IL}) / 2

Figure 19. Input signal measurement reference

All digital I/O switching characteristics, unless otherwise specified, assume that the output pins have the following characteristics.

- C_L=30 pF loads
- Slew rate disabled
- Normal drive strength

5.2.2 Nonswitching electrical specifications

Table 36. Voltage and current operating behaviors (continued)

Symbol	Description	Min.	Max.	Unit	Notes
I_{IN}	Input leakage current (per pin) for full temperature range	—	1	µA	2
I_{IN}	Input leakage current (per pin) at 25 °C	—	0.025	µA	2
I_{IN}	Input leakage current (total all pins) for full temperature range	—	64	µA	2
I_{OZ}	Hi-Z (off-state) leakage current (per pin)	—	1	µA	
R_{PU}	Internal pullup resistors	20	50	kΩ	3

1. PTB0, PTB1, PTC3, PTC4, PTD6, and PTD7 I/O have both high drive and normal drive capability selected by the associated PTx_PCRn[DSE] control bit. All other GPIOs are normal drive only.
2. Measured at V_{DD} = 3.6 V
3. Measured at V_{DD} supply voltage = V_{DD} min and Vinput = V_{SS}

5.2.2.4 Power mode transition operating behaviors

All specifications except t_{POR} and VLLSx → RUN recovery times in the following table assume this clock configuration:

- CPU and system clocks = 48 MHz
- Bus and flash clock = 24 MHz
- HIRC clock mode

Table 37. Power mode transition operating behaviors

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
t_{POR}	After a POR event, amount of time from the point V_{DD} reaches 1.8 V to execution of the first instruction across the operating temperature range of the chip.	—	—	300	µs	
	• VLLS0 → RUN	—	152	166	µs	
	• VLLS1 → RUN	—	152	166	µs	
	• VLLS3 → RUN	—	93	104	µs	
	• LLS → RUN	—	7.5	8	µs	
	• VLPS → RUN	—	7.5	8	µs	
	• STOP → RUN	—	7.5	8	µs	

Table 38. Power consumption operating behaviors (continued)

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
I_{DD_VLPR}	Very-low-power run mode current— 8 MHz LIRC mode, While(1) loop in flash all peripheral clock disable, 4 MHz core / 1 MHz flash, V_{DD} = 3.0 V • at 25 °C	—	212	318	µA	
I_{DD_VLPR}	Very-low-power run mode current—8 MHz LIRC mode, While(1) loop in flash all peripheral clock enable, 4 MHz core / 1 MHz flash, V_{DD} = 3.0 V • at 25 °C	—	302	392.6	µA	
I_{DD_WAIT}	Wait mode current—core disabled, 48 MHz system/24 MHz bus, flash disabled (flash doze enabled), all peripheral clocks disabled, MCG_Lite under HIRC mode, V_{DD} = 3.0 V • at 25 °C	—	1.81	2.12	mA	
I_{DD_WAIT}	Wait mode current—core disabled, 24 MHz system/12 MHz bus, flash disabled (flash doze enabled), all peripheral clocks disabled, MCG_Lite under HIRC mode, V_{DD} = 3.0 V • at 25 °C	—	1.27	1.46	mA	
I_{DD_VLPW}	Very-low-power wait mode current, core disabled, 4 MHz system/ 1 MHz bus and flash, all peripheral clocks disabled, V_{DD} = 3.0 V • at 25 °C	—	156	193.2	µA	
I_{DD_VLPW}	Very-low-power wait mode current, core disabled, 2 MHz system/ 0.5 MHz bus and flash, all peripheral clocks disabled, V_{DD} = 3.0 V • at 25 °C	—	63	100.8	µA	
I_{DD_VLPW}	Very-low-power wait mode current, core disabled, 125 kHz system/ 31.25 kHz bus and flash, all peripheral clocks disabled, V_{DD} = 3.0 V • at 25 °C	—	32	48	µA	
I_{DD_PSTOP2}	Partial Stop 2, core and system clock disabled, 12 MHz bus and flash, V_{DD} = 3.0 V • at 25 °C	—	1.68	2.05	mA	
I_{DD_PSTOP2}	Partial Stop 2, core and system clock disabled, flash doze enabled, 12 MHz bus, V_{DD} = 3.0 V • at 25 °C	—	1.05	1.26	mA	
I_{DD_STOP}	Stop mode current at 3.0 V • at 25 °C and below • at 50 °C • at 85 °C • at 105 °C	— — — —	158.1 171 203.8 251.7	175.81 180.24 228.64 300.06	µA	

Table continues on the next page...

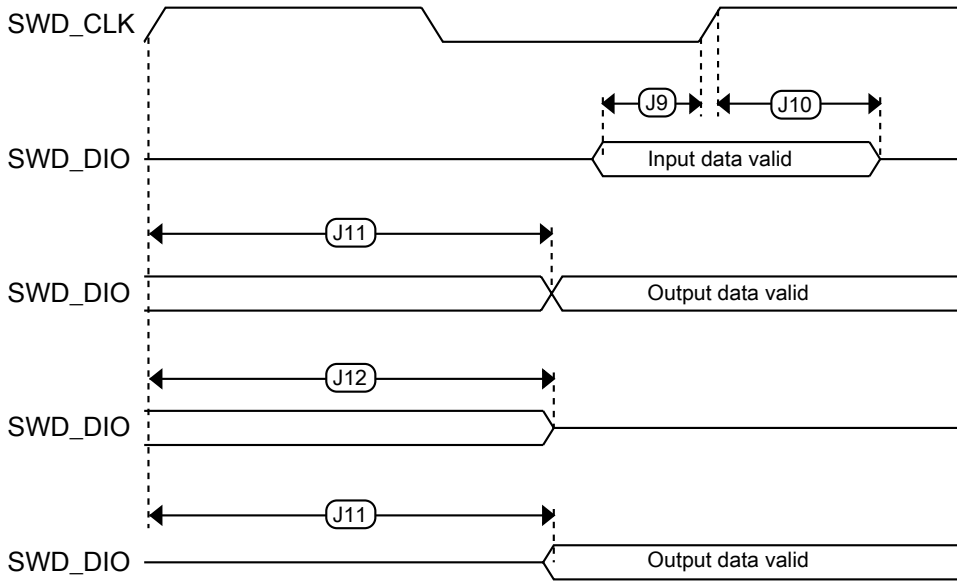


Figure 23. Serial wire data timing

5.3.2 System modules

There are no specifications necessary for the device's system modules.

5.3.3 Clock modules

5.3.3.1 MCG-Lite specifications

Table 46. IRC48M specifications

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
I_{DD48M}	Supply current	—	400	500	µA	
f_{irc48m}	Internal reference frequency	—	48	—	MHz	
$\Delta f_{irc48m\_ol\_lv}$	Open loop total deviation of IRC48M frequency at low voltage (VDD=1.71V-1.89V) over temperature	—	± 0.5	± 1.5	$\%f_{irc48m}$	
$\Delta f_{irc48m\_ol\_hv}$	Open loop total deviation of IRC48M frequency at high voltage (VDD=1.89V-3.6V) over temperature	—	± 0.5	± 1.0	$\%f_{irc48m}$	1
J_{cyc_irc48m}	Period Jitter (RMS)	—	35	150	ps	
$t_{irc48mst}$	Startup time	—	2	3	µs	2

5.3.6.2 CMP and 6-bit DAC electrical specifications

Table 59. Comparator and 6-bit DAC electrical specifications

Symbol	Description	Min.	Typ.	Max.	Unit
V_{DD}	Supply voltage	1.71	—	3.6	V
I_{DDHS}	Supply current, High-speed mode (EN=1, PMODE=1)	—	—	200	µA
I_{DDLS}	Supply current, low-speed mode (EN=1, PMODE=0)	—	—	20	µA
V_{AIN}	Analog input voltage	V_{SS} – 0.3	—	V_{DD}	V
V_{AIO}	Analog input offset voltage	—	—	20	mV
V_H	Analog comparator hysteresis[1]				
	• CR0[HYSTCTR] = 00	—	5	—	mV
	• CR0[HYSTCTR] = 01	—	10	—	mV
	• CR0[HYSTCTR] = 10	—	20	—	mV
	• CR0[HYSTCTR] = 11	—	30	—	mV
V_{CMPOh}	Output high	V_{DD} – 0.5	—	—	V
V_{CMPOl}	Output low	—	—	0.5	V
t_{DHS}	Propagation delay, high-speed mode (EN=1, PMODE=1)	20	50	200	ns
t_{DLS}	Propagation delay, low-speed mode (EN=1, PMODE=0)	80	250	600	ns
	Analog comparator initialization delay[2]	—	—	40	µs
I_{DAC6b}	6-bit DAC current adder (enabled)	—	7	—	µA
INL	6-bit DAC integral non-linearity	–0.5	—	0.5	LSB[3]
DNL	6-bit DAC differential non-linearity	–0.3	—	0.3	LSB

1. Typical hysteresis is measured with input voltage range limited to 0.6 to V_{DD}–0.6 V.
2. Comparator initialization delay is defined as the time between software writes to change control inputs (Writes to CMP_DACCR[DACEN], CMP_DACCR[VRSEL], CMP_DACCR[VOSEL], CMP_MUXCR[PSEL], and CMP_MUXCR[MSEL]) and the comparator output settling to a stable level.
3. 1 LSB = $V_{reference}/64$

Table 62. SPI slave mode timing on slew rate disabled pads (continued)

Num.	Symbol	Description	Min.	Max.	Unit	Note
4	t_{Lag}	Enable lag time	1	—	t_{periph}	—
5	t_{WSPSCK}	Clock (SPSCK) high or low time	t_{periph} - 30	—	ns	—
6	t_{SU}	Data setup time (inputs)	2.5	—	ns	—
7	t_{HI}	Data hold time (inputs)	3.5	—	ns	—
8	t_a	Slave access time	—	t_{periph}	ns	3
9	t_{dis}	Slave MISO disable time	—	t_{periph}	ns	4
10	t_v	Data valid (after SPSCK edge)	—	31	ns	—
11	t_{HO}	Data hold time (outputs)	0	—	ns	—
12	t_{RI}	Rise time input	—	t_{periph} - 25	ns	—
	t_{FI}	Fall time input				
13	t_{RO}	Rise time output	—	25	ns	—
	t_{FO}	Fall time output				

1. For SPI0 f_{periph} is the bus clock (f_{BUS}). For SPI1 f_{periph} is the system clock (f_{SYS}).
2. $t_{periph} = 1/f_{periph}$
3. Time to data active from high-impedance state
4. Hold time to high-impedance state

Table 63. SPI slave mode timing on slew rate enabled pads

Num.	Symbol	Description	Min.	Max.	Unit	Note
1	f_{op}	Frequency of operation	0	$f_{periph}/4$	Hz	1
2	t_{SPSCK}	SPSCK period	4 x t_{periph}	—	ns	2
3	t_{Lead}	Enable lead time	1	—	t_{periph}	—
4	t_{Lag}	Enable lag time	1	—	t_{periph}	—
5	t_{WSPSCK}	Clock (SPSCK) high or low time	t_{periph} - 30	—	ns	—
6	t_{SU}	Data setup time (inputs)	2	—	ns	—
7	t_{HI}	Data hold time (inputs)	7	—	ns	—
8	t_a	Slave access time	—	t_{periph}	ns	3
9	t_{dis}	Slave MISO disable time	—	t_{periph}	ns	4
10	t_v	Data valid (after SPSCK edge)	—	122	ns	—
11	t_{HO}	Data hold time (outputs)	0	—	ns	—
12	t_{RI}	Rise time input	—	t_{periph} - 25	ns	—
	t_{FI}	Fall time input				
13	t_{RO}	Rise time output	—	36	ns	—
	t_{FO}	Fall time output				

1. For SPI0 f_{periph} is the bus clock (f_{BUS}). For SPI1 f_{periph} is the system clock (f_{SYS}).
2. $t_{periph} = 1/f_{periph}$
3. Time to data active from high-impedance state
4. Hold time to high-impedance state

6.1 Hardware design considerations

This device contains protective circuitry to guard against damage due to high static voltage or electric fields. However, take normal precautions to avoid application of any voltages higher than maximum-rated voltages to this high-impedance circuit.

6.1.1 Printed circuit board recommendations

- Place connectors or cables on one edge of the board and do not place digital circuits between connectors.
- Drivers and filters for I/O functions must be placed as close to the connectors as possible. Connect TVS devices at the connector to a good ground. Connect filter capacitors at the connector to a good ground.
- Physically isolate analog circuits from digital circuits if possible.
- Place input filter capacitors as close to the MCU as possible.
- For best EMC performance, route signals as transmission lines; use a ground plane directly under LQFP packages; and solder the exposed pad (EP) to ground directly under QFN packages.

6.1.2 Power delivery system

Consider the following items in the power delivery system:

- Use a plane for ground.
- Use a plane for MCU VDD supply if possible.
- Always route ground first, as a plane or continuous surface, and never as sequential segments.
- Route power next, as a plane or traces that are parallel to ground traces.
- Place bulk capacitance, 10 µF or more, at the entrance of the power plane.
- Place bypass capacitors for MCU power domain as close as possible to each VDD/VSS pair, including VDDA/VSSA and VREFH/VREFL.
- The minimum bypass requirement is to place 0.1 µF capacitors positioned as near as possible to the package supply pins.
- Take special care to minimize noise levels on the VREFH/VREFL inputs. An option is to use the internal reference voltage (output 1.2 V typically) as the ADC reference.

NOTE

The internal reference voltage output (VREFO) is bonded to the VREFH pin on some packages and to PTE30 on other packages. When the VREFO output is used, a 0.1 µF capacitor

is required as a filter. Do not connect any other supply voltage to the pin that has VREFO activated.

6.1.3 Analog design

Each ADC input must have an RC filter as shown in the following figure. The maximum value of R must be RAS max if fast sampling and high resolution are required. The value of C must be chosen to ensure that the RC time constant is very small compared to the sample period.

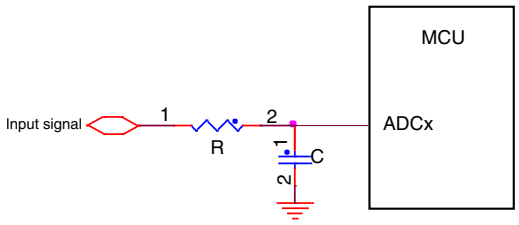


Figure 34. RC circuit for ADC input

High voltage measurement circuits require voltage division, current limiting, and over-voltage protection as shown the following figure. The voltage divider formed by R1 – R4 must yield a voltage less than or equal to VREFH. The current must be limited to less than the injection current limit. Since the ADC pins do not have diodes to VDD, external clamp diodes must be included to protect against transient over-voltages.

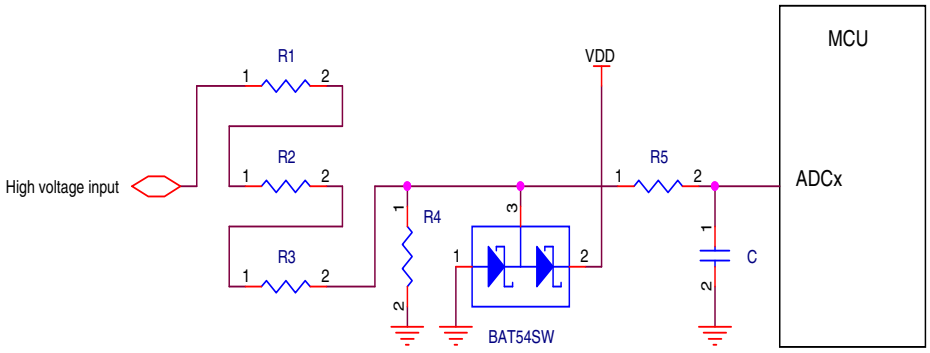


Figure 35. High voltage measurement with an ADC input

6.1.4 Digital design

Ensure that all I/O pins cannot get pulled above VDD (Max I/O is VDD+0.3V).

CAUTION

Do not provide power to I/O pins prior to VDD, especially the RESET_b pin.

- RESET_b pin

  The RESET_b pin is an open-drain I/O pin that has an internal pullup resistor. An external RC circuit is recommended to filter noise as shown in the following figure. The resistor value must be in the range of 4.7 kΩ to 10 kΩ; the recommended capacitance value is 0.1 µF. The RESET_b pin also has a selectable digital filter to reject spurious noise.

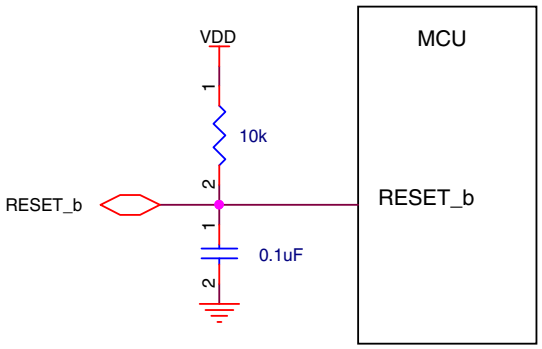


Figure 36. Reset circuit

When an external supervisor chip is connected to the RESET_b pin, a series resistor must be used to avoid damaging the supervisor chip or the RESET_b pin, as shown in the following figure. The series resistor value (RS below) must be in the range of 100 Ω to 1 kΩ depending on the external reset chip drive strength. The supervisor chip must have an active high, open-drain output.

Table 67. Part number fields description (continued)

Field	Description	Values
N	Packaging type	• R = Tape and reel • (Blank) = Trays

1. This package for this product is not yet available. However, it is included in Package Your Way program for Kinetis MCUs. Visit freescale.com/KPYW for more details.

7.4 Example

This is an example part number:

MKL17Z64VLH4

8 Revision history

The following table provides a revision history for this document.

Table 68. Revision history

Rev. No.	Date	Substantial Changes
4	28 January/ 2015	Initial public release • Updated the features and completed the ordering information. • Updated Table 9 - Power consumption operating behaviors with Max. values. • Added a note before Table 9. • Updated Table 17 - IRC48M specifications. • Updated Table 28. VREF full-range (-40 – 105 °C) operating behaviors with Min., Max., and Typical values. • Added Table 36 - I^2C 1Mbit/s timing.
4.1	2 February/ 2015	• Moved the ordering information out of the front page to be a separate chapter. • Added Module signal description table and Package dimension sections.
5	21 April/2015	• 32-pin QFN package is now standard part, added Marking information and thermal attributes of this package • Added Overview chapter • Added Memory map chapter • Added Pin properties • Added a note to the t_{rd1all} in Flash timing specifications — commands • Added a note to the Maximum of f_{SCL} in the fast mode in Inter-Integrated Circuit Interface (I2C) timing • Added a footnote to the Δfirc48m_ol_hv in MCG-Lite specifications • Added Design considerations chapter